

EVVOSEMI[®]

THINK CHANGE DO



ESD



TVS



MOS



LDO



Diode



Sensor



DC-DC

Product Specification

▶ Domestic	Part Number	SN74LVC2G14
▶ Overseas	Part Number	SN74LVC2G14
▶ Equivalent	Part Number	SN74LVC2G14

EV is the abbreviation of name EVVO

General Description

The SN74LVC2G14 is a high performance dual inverter with Schmitt-Trigger inputs operating from a 1.65 to 5.5 V supply. Pin configuration and function are the same as the SN74LVC2G04, but the inputs have hysteresis and, with its Schmitt trigger function, the SN74LVC2G14 can be used as a line receiver which will receive slow input signals.

The SN74LVC2G14 is capable of transforming slowly changing input signals into sharply defined, jitter-free output signals. In addition, it has a greater noise margin than conventional inverters.

The SN74LVC2G14 has hysteresis between the positive-going and the negative-going input thresholds (typically 1V) which is determined internally by transistor ratios and is essentially insensitive to temperature and supply voltage variations.

Features

- Designed for 1.65V to 5.5V V_{CC} Operation
- Over Voltage Tolerant Inputs and Outputs
- LVTTTL Compatible – Interface Capability with 5 V TTL Logic with $V_{CC} = 3V$
- LVCMOS Compatible
- 24 mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current Substantially Reduces System Power Requirements
- Current Drive Capability is 24 mA at the Outputs
- Chip Complexity: FET = 72
- These Devices are Pb-Free and are RoHS Compliant

Pin Configuration

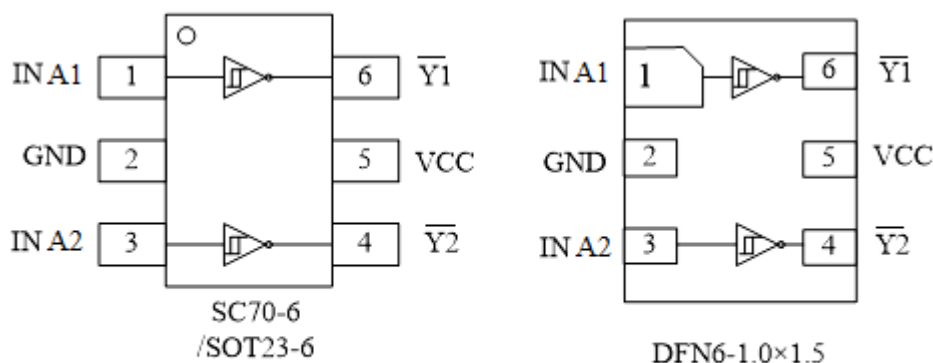
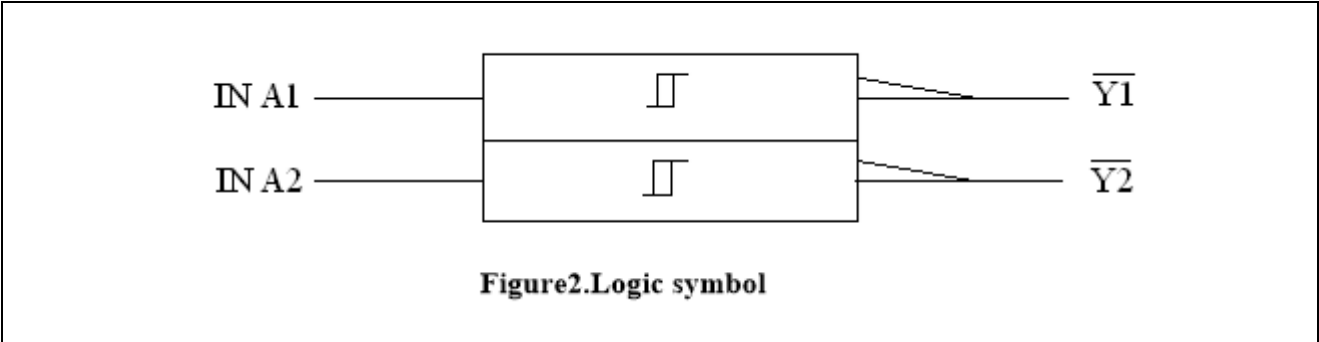


Figure 1. Pinouts (Top View)

Pin Function

PIN	ASSIGNMENT
1	IN A1
2	GND
3	IN A2
4	$\overline{Y2}$
5	VCC
6	$\overline{Y1}$

Block Diagram



Functional Description

Function Table

A Input	Y Output
L	H
H	L

Absolute Maximum Ratings

Symbol	Parameter	Value	Unit
V _{CC}	DC Supply Voltage	-0.5 to 7.0	V
V _I	DC Input Voltage	-0.5 ≤ V _I ≤ +7.0	V
V _O	DC Output Voltage Output in Higher or Low State (Note 1)	-0.5 to V _{CC} + 0.5	V
I _{IK}	DC Input Diode Current V _I < GND	-50	mA
I _{OK}	DC Output Diode Current V _O < GND, V _O > V _{CC}	±50	mA
I _O	DC Output Sink Current	±50	mA
I _{CC}	DC Supply Current per Supply Pin	±100	mA
I _{GND}	DC Ground Current per Supply Pin	±100	mA
T _{STG}	Storage Temperature Range	-65 to 150	°C
T _L	Lead Temperature, 1 mm from Case for 10 Seconds	260	°C
T _J	Junction Temperature Under Bias	150	°C
θ _{JA}	Thermal Resistance	333	°C/W
P _D	Power Dissipation in Still Air at 85 °C	200	mW
MSL	Moisture Sensitivity	Level 1	
F _R	Flammability Rating Oxygen Index:28 to 34	UL94V-0@0.12in	
ESD	ESD Classification Human Body Model (Note 2)	2000	V
	Machine Model (Note3)	200	
	Charged Device Model (Note 4)	N/A	
I _{Latchup}	Latchup Performance Above V _{CC} and Below GND at 125 °C (Note 5)	±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. IO absolute maximum rating must be observed.
2. Tested to EIA/JESD22-A114-A, rated to EIA/JESD22-A114-B.
3. Tested to EIA/JESD22-A115-A, rated to EIA/JESD22-A115-A.
4. Tested to JESD22-C101-A.
5. Tested to EIA/JESD78.

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Unit
V _{CC}	DC Supply Voltage Operating	1.65	5.5	V
	Date Retention	1.5	5.5	
V _{IN}	DC Input Voltage	0	5.5	V
V _{OUT}	DC Output Voltage (High or Low State)	0	5.5	V
T _A	Operating Temperature Range	-55	125	°C
t _r , t _f	Input Rise and Fall Time V _{CC} = 2.5 V ± 0.2 V	0	20	ns/V
	V _{CC} = 3.0 V ± 0.3 V	0	10	
	V _{CC} = 5.0 V ± 0.5 V	0	5	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended.

Electrical Characteristics

DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Condition	VCC(V)	TA = 25 °C			-55°C ≤ TA ≤ 125°C		Unit
				Min	Typ	Max	Min	Max	
V _{IH}	High-Level Input Voltage		1.65to1.95 2.3 to 5.5	0.75V _{CC} 0.7V _{CC}			0.75V _{CC} 0.7V _{CC}		V
V _{IL}	Low-Level Input Voltage		1.65to1.95 2.3 to 5.5			0.25V _{CC} 0.3V _{CC}		0.25V _{CC} 0.3V _{CC}	V
V _{OH}	High-Level Output Voltage V _{IN} = V _{IL}	I _{OH} = -100uA	1.65to5.5	V _{CC} -0.1	V _{CC}		V _{CC} -0.1		V
		I _{OH} = -3mA	1.65	1.29	1.52		1.29		
		I _{OH} = -8mA	2.3	1.9	2.1		1.9		
		I _{OH} = -12mA	2.7	2.2	2.4		2.2		
		I _{OH} = -16mA	3.0	2.4	2.7		2.4		
		I _{OH} = -24mA	3.0	2.3	2.5		2.3		
		I _{OH} = -32mA	4.5	3.8	4.0		3.8		
V _{OL}	Low-Level Output Voltage V _{IN} = V _{IH}	I _{OH} = 100uA	1.65to5.5		0.0	0.1		0.1	V
		I _{OL} = 3mA	1.65		0.08	0.24		0.24	
		I _{OL} = 8mA	2.3		0.20	0.3		0.3	
		I _{OL} = 12mA	2.7		0.22	0.4		0.4	
		I _{OL} = 16mA	3.0		0.28	0.4		0.4	
		I _{OL} = 24mA	3.0		0.38	0.55		0.55	
		I _{OL} = 32mA	4.5		0.42	0.55		0.55	
I _{IN}	Input Leakage Current	V _{IN} = 5.5V or GND	0 to 5.5		±0.1			±1.0	uA
I _{OFF}	Power Off Leakage Current	V _{IN} = 5.5V or V _{OUT} = 5.5V	0			1		10	uA
I _{CC}	Quiescent Supply Current	V _{IN} = 5.5V or GND	5.5					10	uA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

**AC ELECTRICAL CHARACTERISTICS $t_r=t_f= 2.5\text{ns}$; $C_L = 50\text{pF}$;
 $R_L = 500\ \Omega$**

Symbol	Parameter	Condition	$V_{CC}(\text{V})$	$T_A = 25\ ^\circ\text{C}$			$-55^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$		Unit
				Min	Typ	Max	Min	Max	
t_{PLH} t_{PHL}	Propagation Delay (Figure 3 and 4)	$R_L = 1\text{M}\Omega$ $C_L = 15\text{ pF}$	1.65	2.0	5.3	11.4	2.0	12.0	ns
			1.8	2.0	4.4	9.5	2.0	10.0	
		$R_L = 1\text{M}\Omega$ $C_L = 15\text{ pF}$	2.5 ± 0.2	0.2	3.5	6.5	0.8	4.1	
		$R_L = 1\text{M}\Omega$ $C_L = 15\text{ pF}$	3.3 ± 0.3	0.8	2.1	4.5	0.5	3.7	
		$R_L = 500\Omega$ $C_L = 50\text{ pF}$		1.2	2.9	5.5	1.5	5.2	
		$R_L = 1\text{M}\Omega$ $C_L = 15\text{ pF}$	5.0 ± 0.5	0.5	1.8	3.9	0.5	4.1	
		$R_L = 500\Omega$ $C_L = 50\text{ pF}$		0.8	2.4	4.3	0.8	4.5	

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typical	Unit
C_{IN}	Input Capacitance	$V_{CC} = 5.5\text{ V}, V_I = 0\text{ V or } V_{CC}$	>2.5	pF
C_{PD}	Power Dissipation Capacitance (Note 6)	10MHz, $V_{CC} = 3.3\text{ V}, V_I = 0\text{ V or } V_{CC}$	4	pF
		10MHz, $V_{CC} = 5.5\text{ V}, V_I = 0\text{ V or } V_{CC}$	4	

6. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation:

$I_{CC(OPR)} = C_{PD} \cdot V_{CC} \cdot f_{in} + I_{CC} \cdot C_{PD}$ is used to determine the no-load dynamic power consumption;

$P_D = C_{PD} \cdot V_{CC}^2 \cdot f_{in} + I_{CC} \cdot V_{CC} \cdot Fig.$

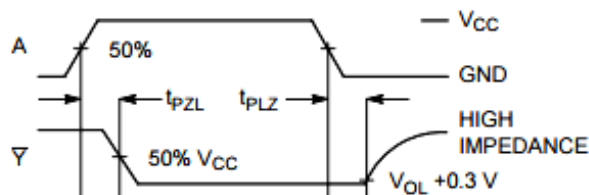


Figure 3. Switching Waveforms

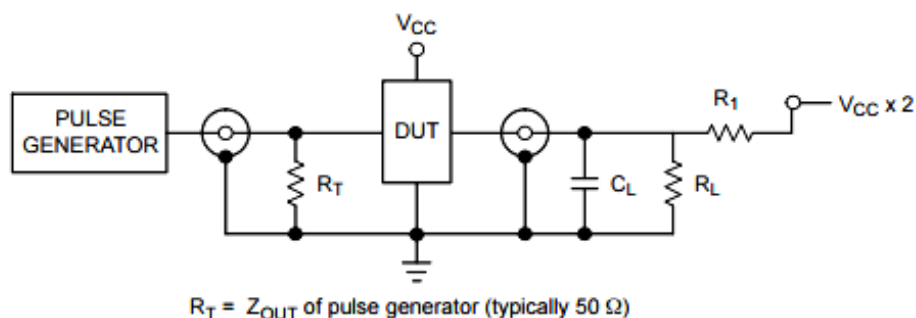
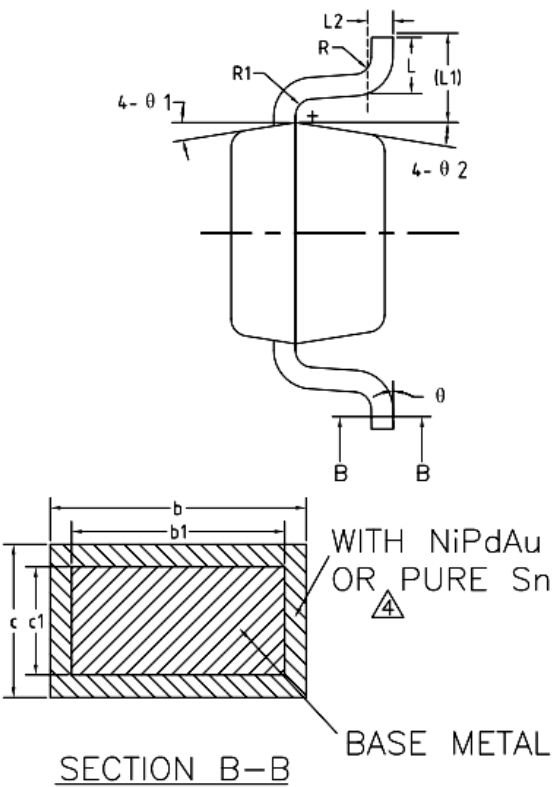
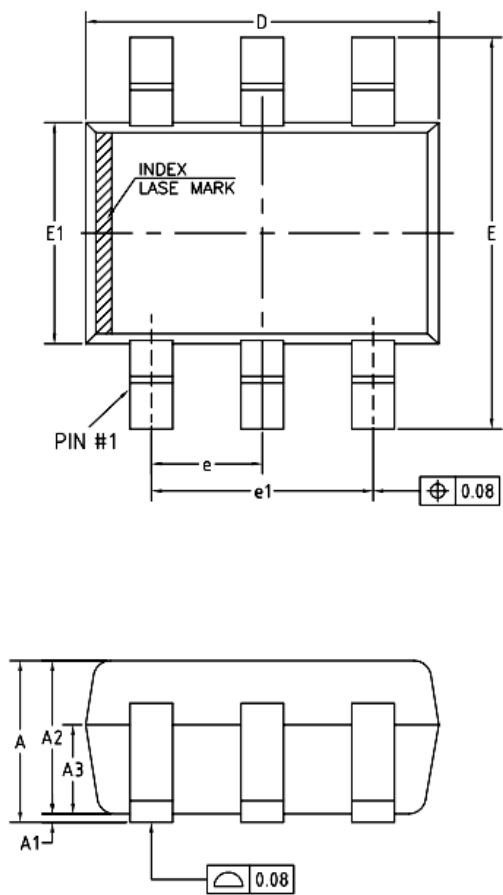


Figure 4. Test Circuit

SN74LVC2G14

Package Dimension

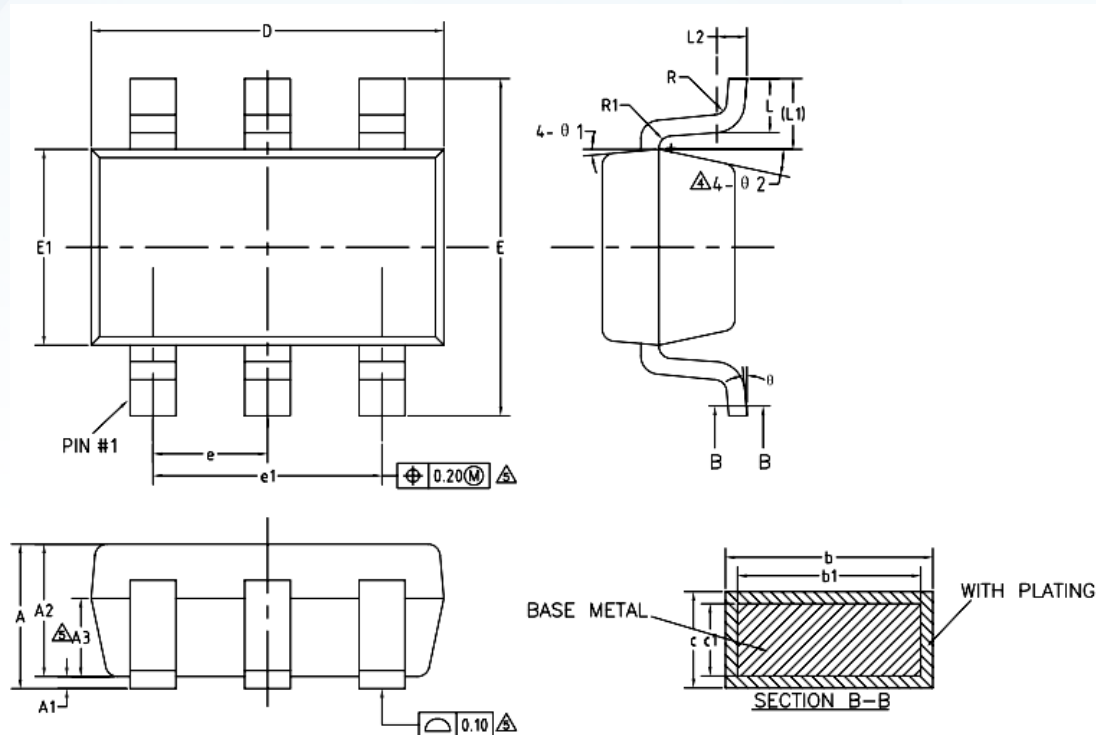
SC70-6



COMMON DIMENSIONS
(UNITS OF MEASURE=MILLIMETER)

SYMBOL		MIN	NOM	MAX
A		0.85	—	1.05
A1		0	—	0.10
A2		0.80	0.90	1.00
A3		0.47	0.52	0.57
b	NiPdAu	0.22	—	0.29
	PURE Sn	0.23	—	0.33
b1		0.22	0.25	0.28
c	NiPdAu	0.115	—	0.15
	PURE Sn	0.12	—	0.18
c1		0.115	0.13	0.14
D		2.02	2.07	2.12
E		2.20	2.30	2.40
E1		1.25	1.30	1.35
e		0.60	0.65	0.70
e1		1.20	1.30	1.40
L		0.28	0.33	0.38
L1	0.50REF			
L2	0.15BSC			
R		0.10	—	—
R1		0.10	—	0.25
θ		0°	—	8°
θ 1		6°	9°	12°
θ 2		6°	9°	12°

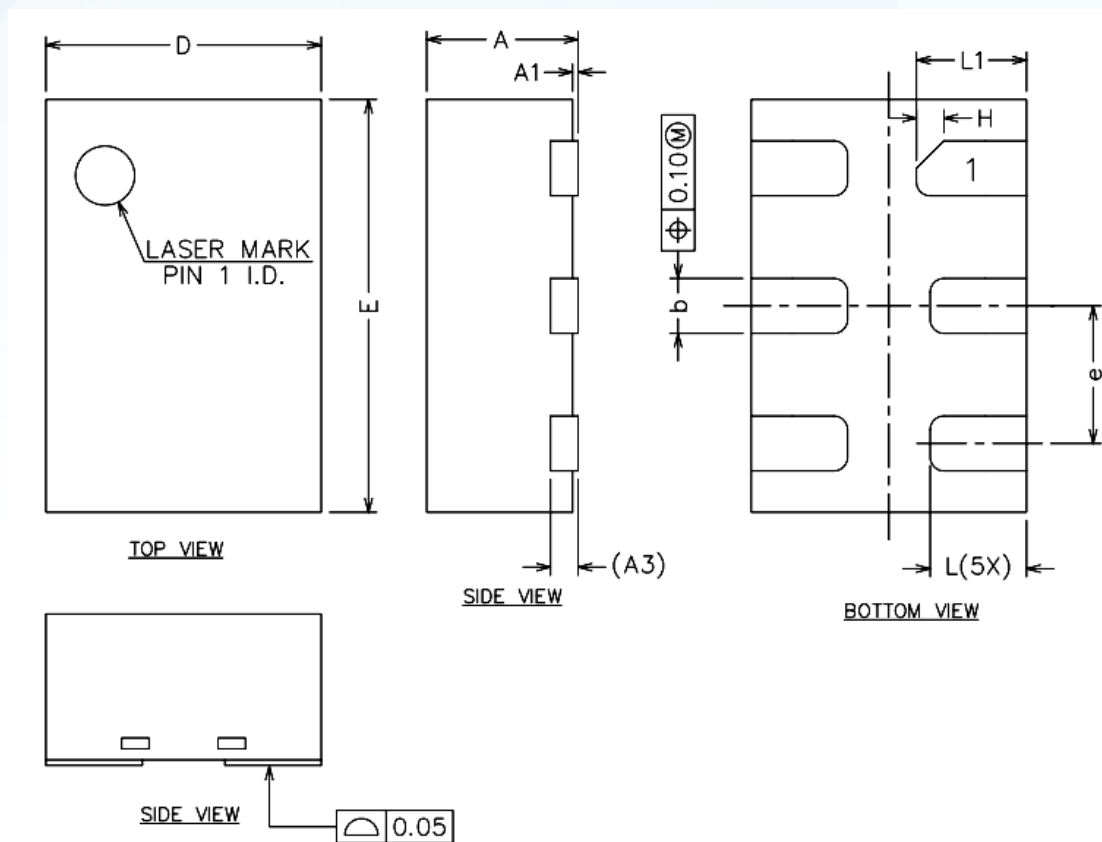
SOT23-6



COMMON DIMENSIONS
(UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX
A	—	—	1.25
A1	0	—	0.15
A2	1.00	1.10	1.20
A3	0.60	0.65	0.70
b	0.36	—	0.50
b1	0.36	0.38	0.45
c	0.14	—	0.20
c1	0.14	0.15	0.16
D	2.826	2.926	3.026
E	2.60	2.80	3.00
E1	1.526	1.626	1.726
e	0.90	0.95	1.00
e1	1.80	1.90	2.00
L	0.35	0.45	0.60
L1	0.59REF		
L2	0.25BSC		
R	0.10	—	—
R1	0.10	—	0.20
θ	0°	—	8°
θ 1	3°	5°	7°
θ 2	6°	—	14°

DFN6



COMMON DIMENSIONS
(UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX
A	0.50	—	0.60
A1	0.00	0.02	0.05
A3	0.10REF		
b	0.15	0.20	0.25
D	0.90	1.00	1.10
E	1.40	1.50	1.60
e	0.40	0.50	0.60
H	0.10REF		
L	0.30	0.35	0.40
L1	0.35	0.40	0.45

Ordering information

Order code	Marking code	Package	Baseqty	Deliverymode
SN74LVC2G14DBVR	C145	SOT23-6	3000	Tape and reel
SN74LVC2G14DCKR	CF5	SC70-6	3000	Tape and reel
SN74LVC2G14DRYR	CF	DFN6	3000	Tape and reel

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